

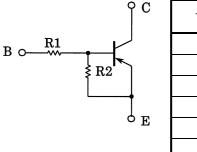
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

### RN2101,RN2102,RN2103 RN2104,RN2105,RN2106

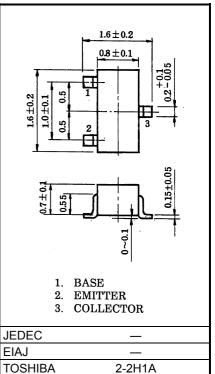
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1101~RN1106

#### **Equivalent Circuit and Bias Resister Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN2101	4.7	4.7
RN2102	10	10
RN2103	22	22
RN2104	47	47
RN2105	2.2	47
RN2106	4.7	47
	RN2101 RN2102 RN2103 RN2104 RN2105	RN2101 4.7   RN2102 10   RN2103 22   RN2104 47   RN2105 2.2



Weight: 2.4mg

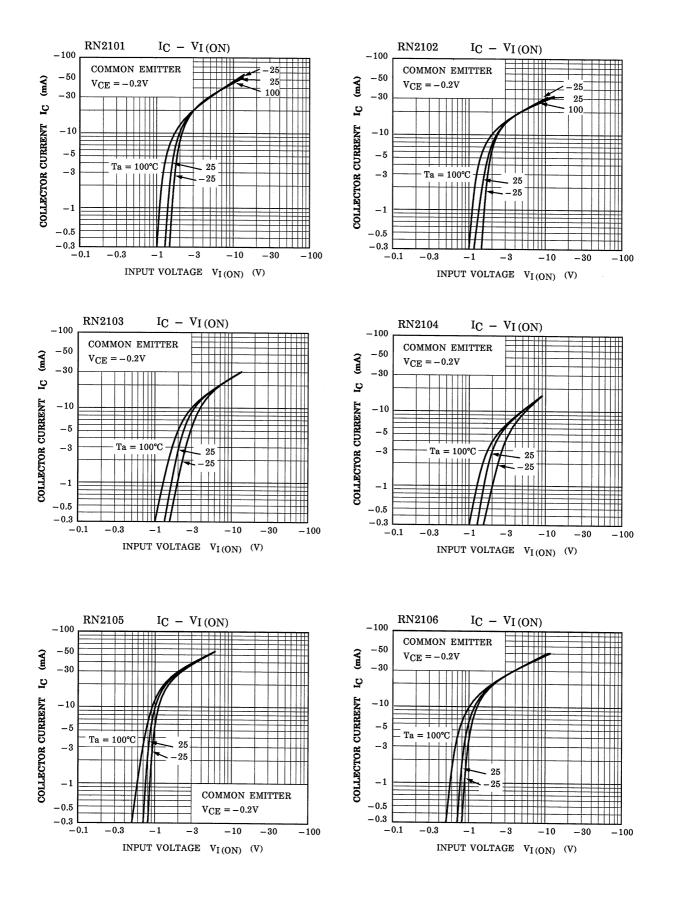
### Maximum Ratings (Ta = 25°C)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN2101~2106	V <sub>CBO</sub>	-50	V	
Collector-emitter voltage		V <sub>CEO</sub>	-50	V	
Emitter-base voltage	RN2101~2104		-10	V	
	RN2105, 2106	V <sub>EBO</sub>	-5		
Collector current		Ι <sub>C</sub>	-100	mA	
Collector power dissipation	RN2101~2106	P <sub>C</sub>	100	mW	
Junction temperature	RINZ 101~2100	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

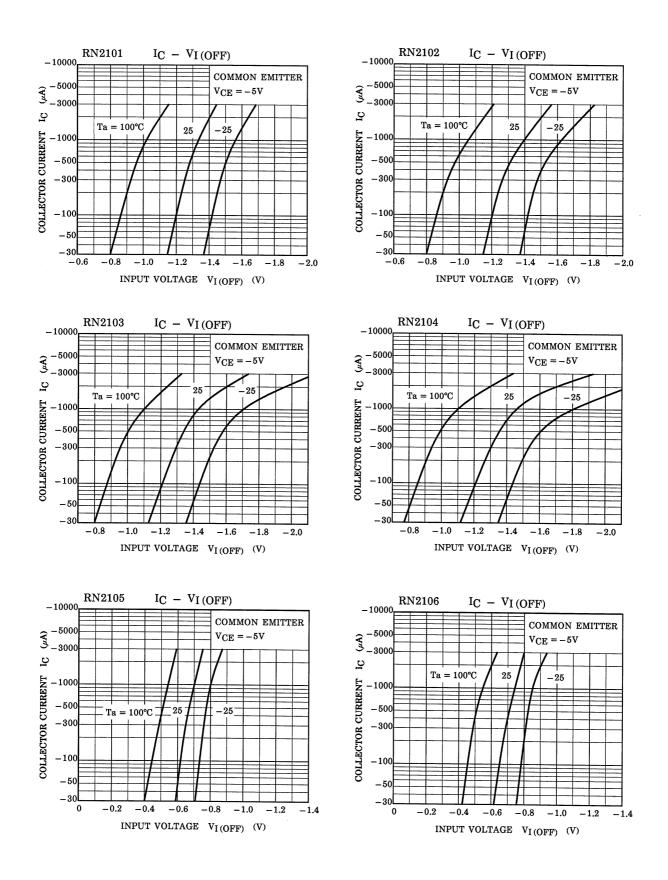
Unit: mm

Electrical Characteristics (Ta = 25°C)

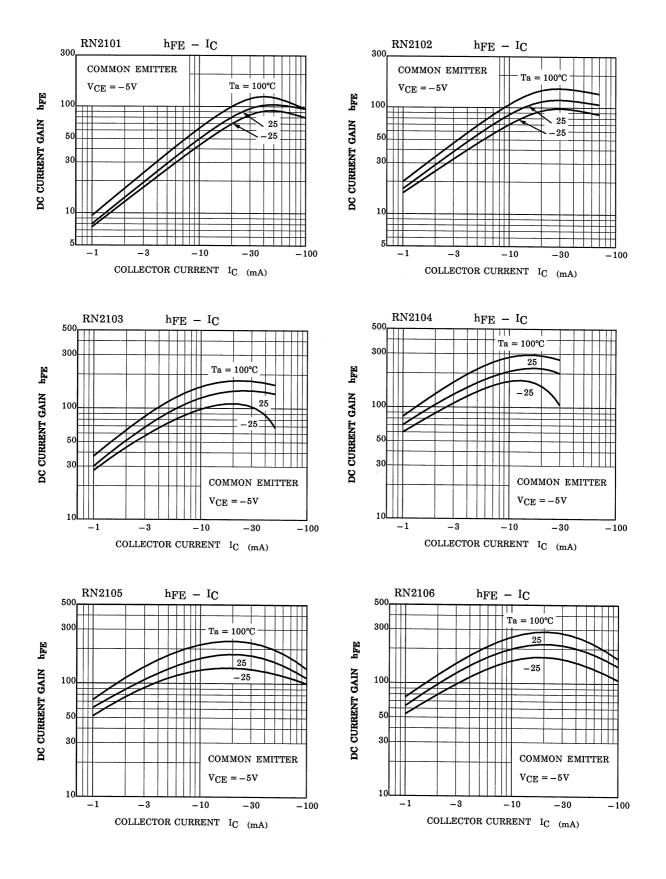
Character	istic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN0404 0400	I <sub>CBO</sub>		$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
	RN2101~2106			$V_{CE} = -50V, I_B = 0$	_	_	-500	
	RN2101	IEBO		V <sub>EB</sub> = -10V, I <sub>C</sub> = 0	-0.82	—	-1.52	mA
Emitter cut-off current	RN2102		_		-0.38	—	-0.71	
	RN2103				-0.17	_	-0.33	
	RN2104				-0.082	_	-0.15	
	RN2105				-0.078	—	-0.145	
	RN2106			$V_{EB} = -5V, I_C = 0$	-0.074	_	-0.138	
	RN2101				30	_	_	
	RN2102			Vor = -5V	50	_	_	
	RN2103				70	_	_	
DC current gain	RN2104	h <sub>FE</sub>	-	V <sub>CE</sub> = −5V, I <sub>C</sub> = −10mA	80	_	_	
	RN2105				80	_	_	
	RN2106				80	_	_	
Collector-emitter saturation voltage	RN2101~2106	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = −5mA, I <sub>B</sub> = −0.25mA	_	-0.1	-0.3	V
	RN2101	V <sub>I (ON)</sub>		V <sub>CE</sub> = -0.2V, I <sub>C</sub> = -5mA	-1.1	_	-2.0	V
	RN2102				-1.2	_	-2.4	
Input voltage (ON)	RN2103		_		-1.3	_	-3.0	
	RN2104				-1.5	_	-5.0	
	RN2105				-0.6	_	-1.1	
	RN2106				-0.7	_	-1.3	
	RN2101~2104	VI (OFF) —		V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1mA	-1.0	_	-1.5	V
Input voltage (OFF)	RN2105, 2106		_		-0.5	_	-0.8	
Transition frequency	RN2101~2106	f <sub>T</sub>	-	V <sub>CE</sub> = −10V, I <sub>C</sub> = −5mA	-	200	_	MHz
Collector Output capacitance	RN2101~2106	C <sub>ob</sub>	_	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
Input resistor	RN2101	R1 —		-	3.29	4.7	6.11	kΩ
	RN2102		_		7	10	13	
	RN2103				15.4	22	28.6	
	RN2104				32.9	47	61.1	
	RN2105				1.54	2.2	2.86	
	RN2106				3.29	4.7	6.11	
Resistor ratio	RN2101~2104		1		0.9	1.0	1.1	
	RN2105	R1/R2	_		0.0421	0.0468	0.0515	
	RN2106				0.09	0.1	0.11	



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Type Name	Marking
RN2001	Type Name Y A
RN2102	Type Name Y B
RN2103	Type Name Y C
RN2104	Type Name Y D U U
RN2105	Type Name Y E H H
RN2106	Type Name Y F H H

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